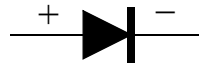


Diodes



- Schematic symbol:



- Signal diodes, power diodes

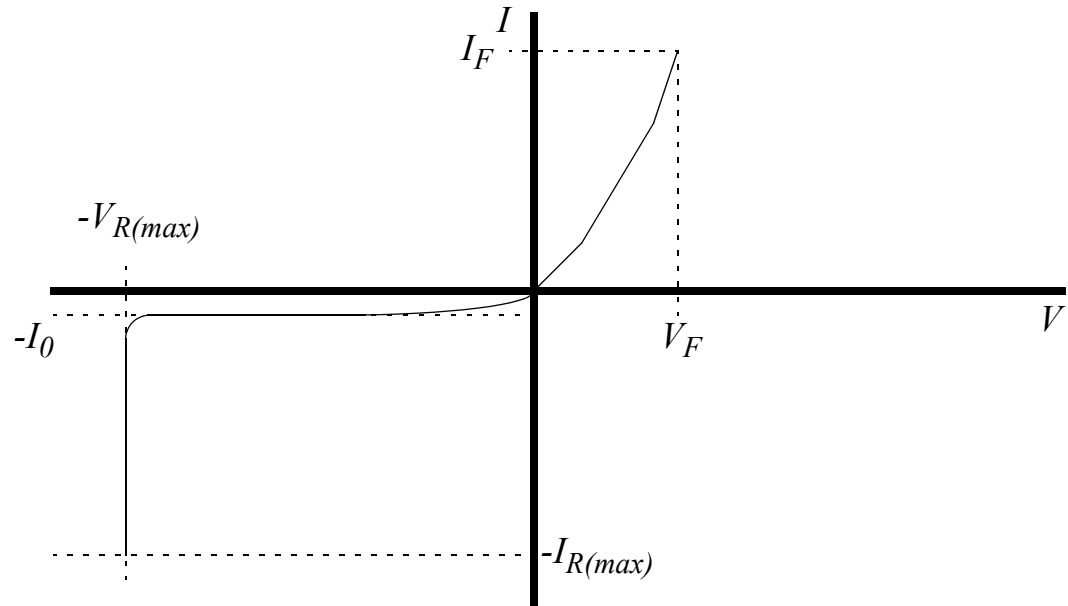
$V_{R(max)}$: Maximum reverse voltage

$I_{R(max)}$: Maximum reverse current

V_F : Typical forward voltage drop

Maximum power dissipated

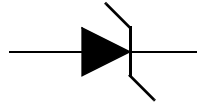
Capacitance



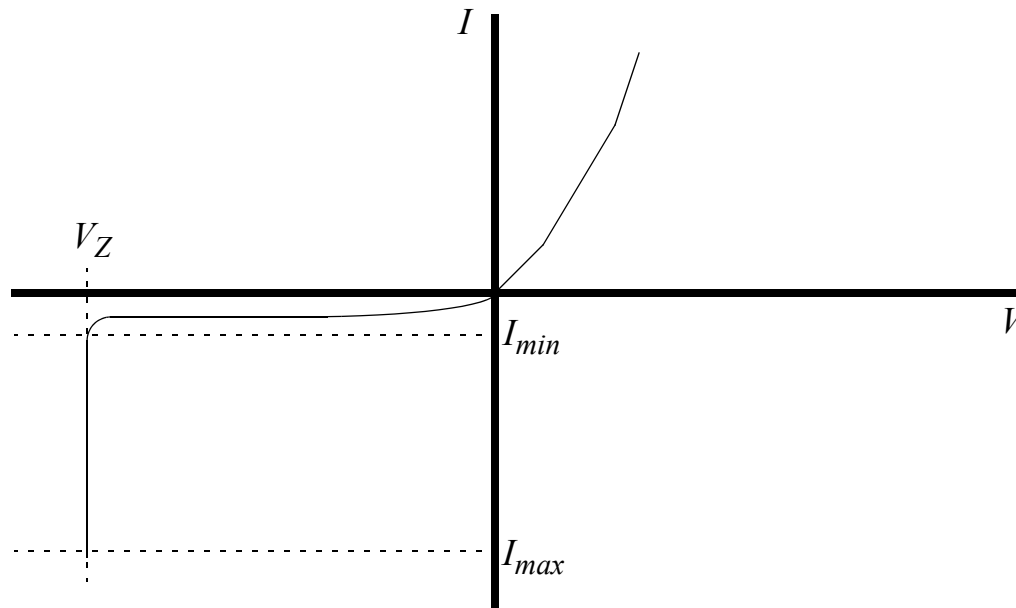
Zener Diode



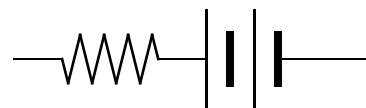
- Schematic symbol:



- Zener diodes have well defined reverse breakdown voltages and they are designed to run there.
- Voltage change is very small (1%) over a wide range of operating current.



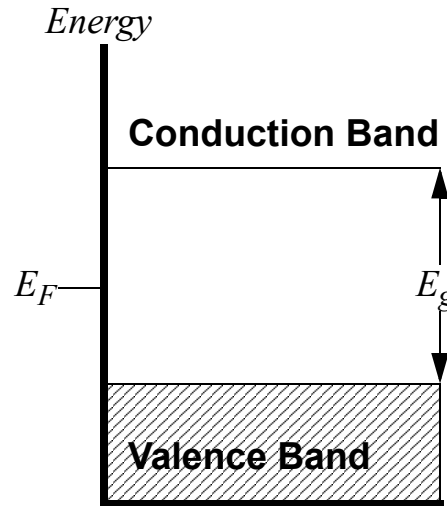
- Equivalent circuit: battery and a resistor.



Photoconduction



- Electrons can be excited from a valence band to a conduction band by photons.



$$E_g = 1.09 \text{ eV in Silicon (Si)}$$

$$E_g = 0.72 \text{ eV in Germanium (Ge)}$$

- The minimum energy of a photon needed to excite an electron across the gap is equal to the energy of the gap. the frequency of that photon is given by

$$E_g = h\nu = hc/\lambda$$

$$\text{In Si: } \lambda = hc/E_g = (1.24 \text{ } \mu\text{m-eV})/(1.09 \text{ eV}) = 1140 \text{ nm}$$

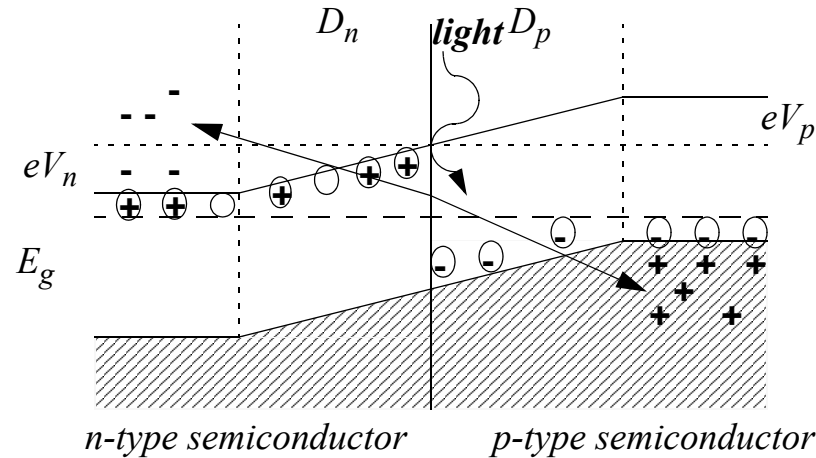
$$\text{In Ge: } \lambda = (1.24 \text{ } \mu\text{m-eV})/(0.72 \text{ eV}) = 1720 \text{ nm}$$

- These wavelengths are in the near-infrared. Visible light is more energetic (350 to 700 nm).

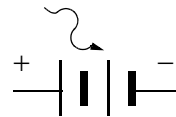
Photovoltaic Diode



- Light falling on a p-n junction can create electrons and holes



- Electrons move to the n-type material, holes to the p-type material.
- The electrons and holes create a potential between the two sides of the junction. This appears as a reverse current I_L .
- A photocell acts like a battery.



- Solar cells connect multiple photocells in series to get the desired output voltage, and in parallel to get the needed current.
- At 10 % efficiency a solar battery can deliver 100 W/m^2 . Averaged over a real day with real weather reduces this.

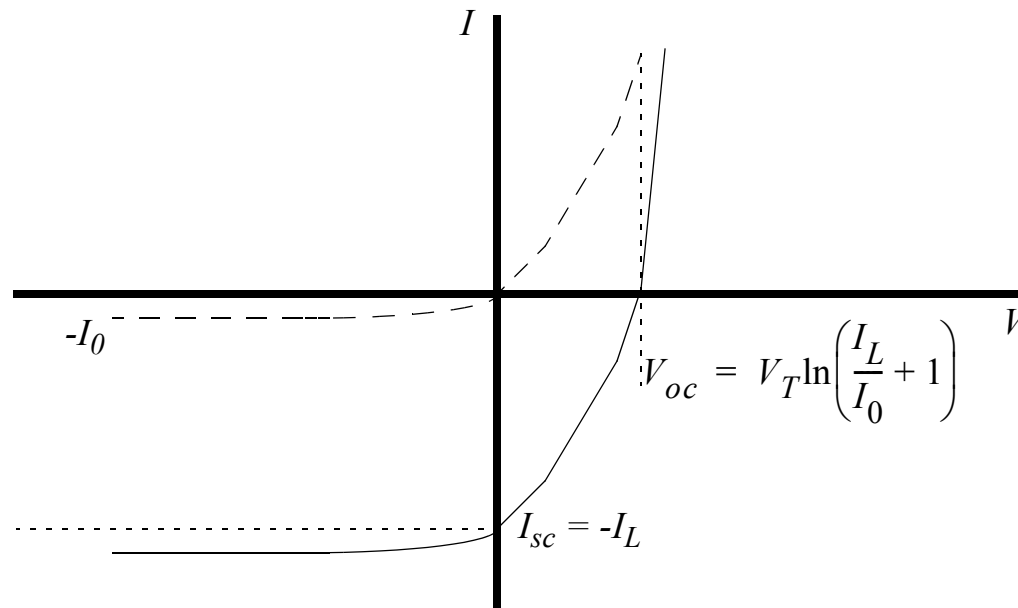
Photocurrent



- The total current for the photovoltaic diode is

$$I = I_0(e^{V/V_T} - 1) - I_L$$

Graphically



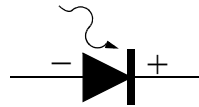
- The equivalent voltage is typically 0.6 V for silicon.
- $V_D = 0.5 - 0.6$ V “diode drop”
- The theoretical maximum voltage is equal to gap voltage V_g , but the real voltage is determined by the current.

Photodiode

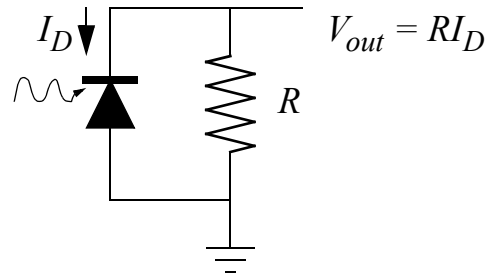


Photodiode as a Light Meter

- Photodiode schematic symbol.



- A resistor converts the current to a voltage

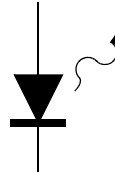


- Typical currents are $1 \mu\text{A}/\mu\text{W}$ incident light.

Light Emitting Diode (LED)



- Forward biased diode, loses energy as light as well as heat.
- Schematic symbol

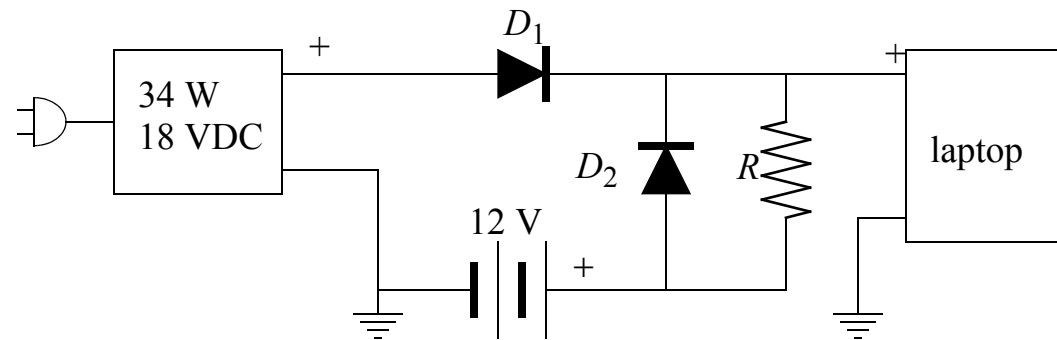


- An ohmmeter can be used to check the polarity
- Voltage requirements: turn on at 1.7 V (1.5 V - 2.5 V).
- Current requirements: 1 mA is dim, 10-20 mA is bright.

Diode Gates



- Diodes can be used to select the higher of two voltages
- Example: battery backup for a laptop

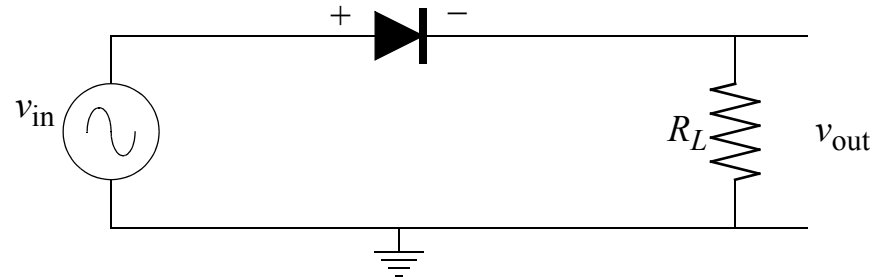


- If the power cord is plugged in, current flows through D_1 and the input voltage to the laptop is 17.4 V. D_2 doesn't conduct since 17.4 V is greater than 12 V.
- If the power cord is unplugged, there is no current through D_1 so D_2 conducts and there is 11.4 V to the laptop.
- The resistor R will have a current in it if the power cord is plugged in. The current is $(17.4 \text{ V} - 12 \text{ V})/R$. If it takes 10 mA of current to charge the 12 V battery, then $R = 5.4 \text{ V}/10 \text{ mA} = 540 \Omega$.

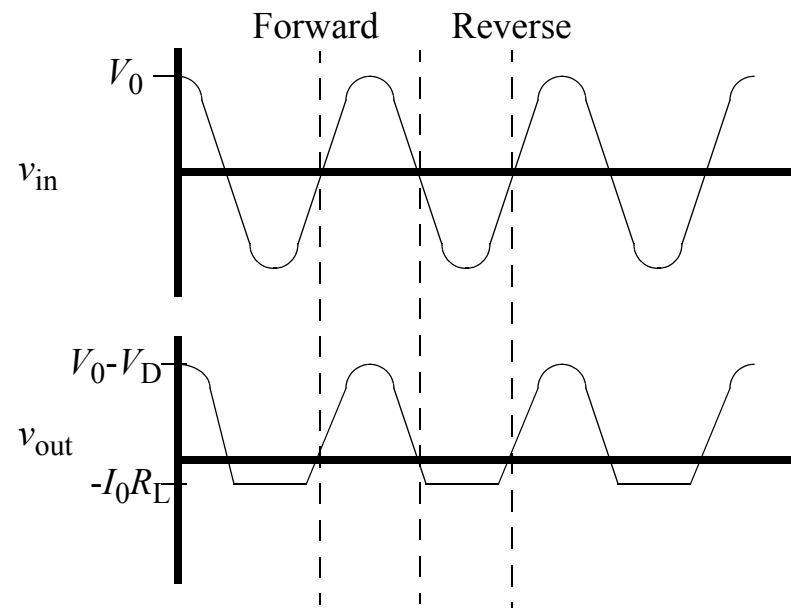
Half-wave Rectifier



- Single diode, AC signal



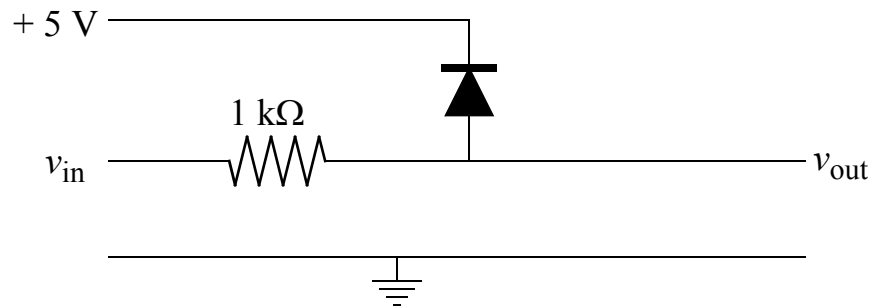
- Forward biased the signal passes, reverse biased the signal is blocked



Diode Clamp

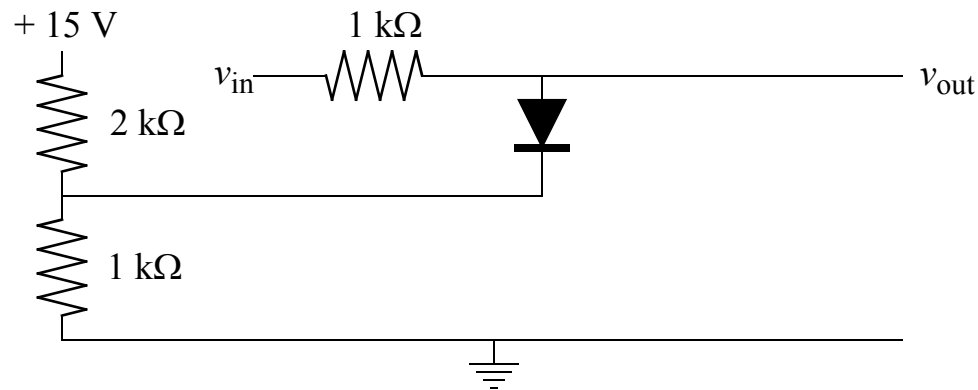


- Cutoff current at voltages other than ground



If $v_{in} > 5.6 \text{ V}$, $v_{out} = 5.6 \text{ V}$.

- The reference voltage can be set with a voltage divider



- The voltage divider has a Thevenin equivalent circuit of 5 V and 670 Ω
- The input resistor then forms a divider with the 670 Ω and not all the current goes through the diode. Use $R_{input} \gg R_{divider}$